

## **Features**

- 1700-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Halogen-Free; RoHS Compliant

#### **Benefits**

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway







T0247-2L **Package** 



Part Number	Package	Marking
HC3D10170H	TO247-2L	HC3D10170H

### **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
$V_{RRM}$	Repetitive Peak Reverse Voltage	1700	V		
V <sub>RSM</sub>	Surge Peak Reverse Voltage	1700	V		
V <sub>DC</sub>	DC Blocking Voltage	1700	V		
$I_{_{F}}$	Continuous Forward Current	14.4	А	T <sub>c</sub> <135°C	
I <sub>FRM</sub>	Repetitive Peak Forward Surge Current	45 26	А	$T_c$ =25°C, $t_p$ =10 ms, Half Sine Wave, D=1 $T_c$ =110°C, $t_p$ =10 ms, Half Sine Wave, D=1	
$I_{\scriptscriptstyle{FSM}}$	Non-Repetitive Peak Forward Surge Current	55 41	А	$T_c$ =25°C, $t_p$ =10ms, Half Sine Wave, D=1 $T_c$ =110°C, $t_p$ =10 ms, Half Sine Wave, D=1	
P <sub>tot</sub>	Power Dissipation	231 100	W	T <sub>c</sub> =25°C T <sub>c</sub> =110°C	
T <sub>c</sub>	Maximum Case Temperature	135	°C		
T,	Operating Junction Range	-55 to +175	°C		
T <sub>stg</sub>	Storage Temperature Range	-55 to +135	°C		
	TO-247 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	



### **Electrical Characteristics**

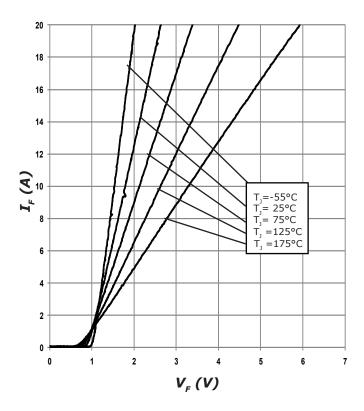
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V <sub>F</sub>	Forward Voltage	1.7 3	2 3.5	V	$I_F = 10 \text{ A } T_J = 25^{\circ}\text{C}$ $I_F = 10 \text{ A } T_J = 175^{\circ}\text{C}$	
I <sub>R</sub>	Reverse Current	20 100	60 300	μΑ	V <sub>R</sub> = 1700 V T <sub>J</sub> =25°C V <sub>R</sub> = 1700 V T <sub>J</sub> =175°C	
Q <sub>c</sub>	Total Capacitive Charge	96		nC	$V_{R} = 1700 \text{ V, } I_{F} = 10 \text{ A}$ $di/dt = 200 \text{ A/}\mu\text{s}$ $T_{J} = 25^{\circ}\text{C}$	
С	Total Capacitance	827 78 41		pF	$egin{array}{l} V_R = 0 \ V, \ T_J = 25^{\circ}\text{C}, \ f = 1 \ \text{MHz} \\ V_R = 200 \ V, \ T_J = 25^{\circ}\text{C}, \ f = 1 \ \text{MHz} \\ V_R = 800 \ V, \ T_J = 25^{\circ}\text{C}, \ f = 1 \ \text{MHz} \\ \end{array}$	

#### Note:

#### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit
$R_{_{ heta JC}}$	Thermal Resistance from Junction to Case	0.65	°C/W

### **Typical Performance**





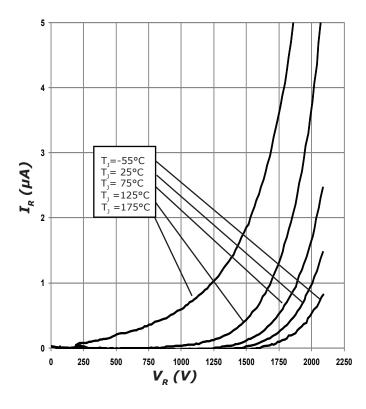
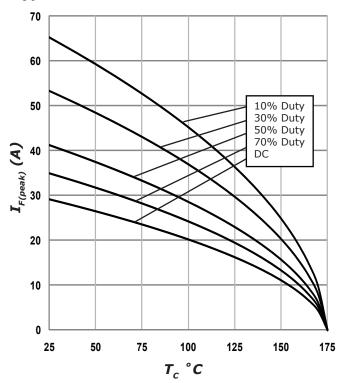


Figure 2. Reverse Characteristics

<sup>1.</sup> This is a majority carrier diode, so there is no reverse recovery charge.



### **Typical Performance**



200 150 50 0 25 50 75 100 125 150 175 T<sub>C</sub> °C

250

Figure 3. Current Derating

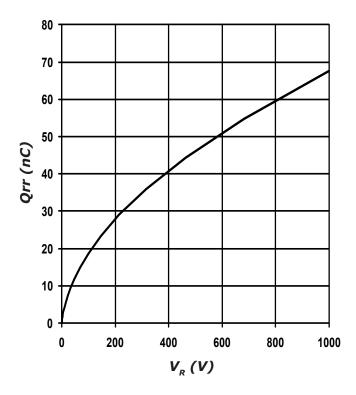


Figure 4. Power Derating

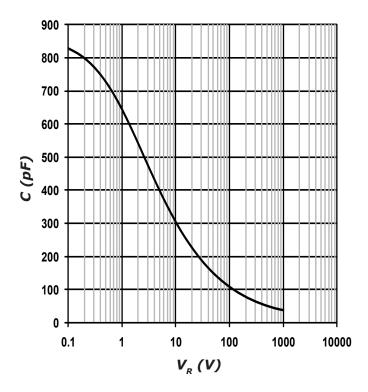
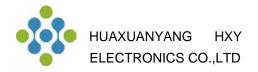


Figure 5. Recovery Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage



# **Typical Performance**

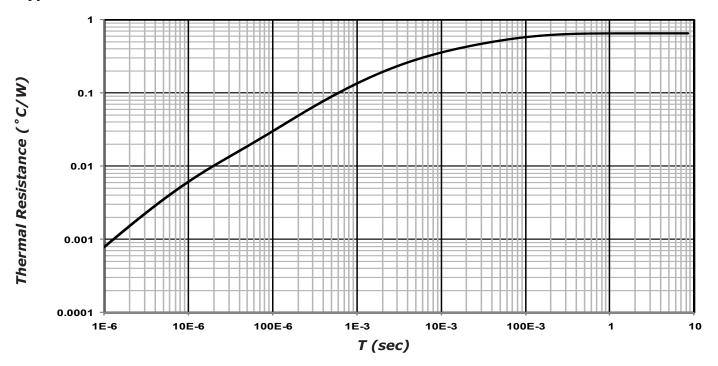
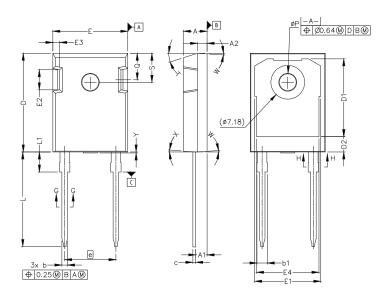


Figure 7. Transient Thermal Impedance

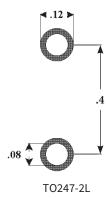
# **Package Dimensions**

Package: TO247-2L All dimensions in mm.



	MILLIM	ETERS	INC	HES		
SYM	MIN	MAX	MIN	MAX		
A	4.83	5.21	.190	.205		
A1	2.29	2.54	.090	.100		
A2	1.91	2.16	.075	.085		
b'	1.07	1.28	.042	.050		
b	1.07	1.33	.042	.052		
bl	1.91	2.41	.075	.095		
b2	1.91	2.16	.075	.085		
c'	0.55	0.65	.022	.026		
С	0.55	0.68	.022	.027		
D	20.80	21.10	.819	.831		
D1	16.25	17.35	.640	.683		
D2	2.86	3.16	.112	.124		
Е	15.75	16.13	.620	.635		
E1	13.10	14.15	.516	.557		
E2	3.68	5.10	.145	.201		
E3	1.00	1.90	.039	.075		
E4	12.38	13.43	.487	.529		
e	10.88	BSC	.428 BSC			
L	19.81	20.32	.780	.800		
L1	4.10	4.40	.161	.173		
φP	3.51	3.65	.138	.144		
Q	5.49	6.00	.216	.236		
S	6.04	6.30	.238	.248		
T		17.5° R	EF.			
W		3.5° REF.				
X		4° REF.				
Y	0	0.50	0	0.020		

# **Recommended Solder Pad Layout**



all units are in inches

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